imall

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ZVNL120G

Product Summary

| V _(BR) dss | Rds(on) | Ι _D Τ _A = +25°C |
|-----------------------|-----------------------------|--|
| 200V | 10Ω @ V _{GS} = 10V | 320mA |

Description

This new generation trench MOSFET features a unique structure combining the benefits of low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Applications

• Off-line Power Supply Start-up Circuitry

200V N-CHANNEL ENHANCEMENT MODE MOSFET

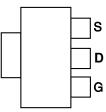
Features and Benefits

- High Voltage
- Low On-resistance
- Fast Switching Speed
- Low Gate Drive
- Low Threshold
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

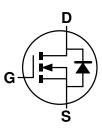
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (3)
- Weight: 0.112 grams (Approximate)









Equivalent Circuit

Ordering Information (Note 4)

| Part Number | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-------------|---------|--------------------|-----------------|-------------------|
| ZVNL120GTA | ZVNL120 | 7 | 12 | 1,000 |
| ZVNL120GTC | ZVNL120 | 13 | 12 | 4,000 |

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

D

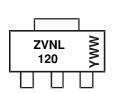
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



SOT223

ZVNL120 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5 = 2015) WW or \overline{WW} = Week Code (01~53)



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|------------------|-------|------|
| Drain-Source Voltage | V _{DSS} | 200 | V |
| Gate-Source Voltage | V _{GSS} | ±20 | V |
| Continuous Drain Current (V _{GS} = 10V, T _A = +25°C) | I _D | 320 | mA |
| Pulsed Drain Current | I _{DM} | 2 | А |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|----------|-------------|------|
| Power Dissipation at $T_A = +25^{\circ}C$ (Note 5) | PD | 2.0 | W |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|-----|-----|-----------|------|---|--|
| OFF CHARACTERISTICS | | | | | • | · | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 200 | - | - | V | $V_{GS} = 0V, I_D = 1mA$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | - | - | 10 100 | μA | $V_{DS} = 200V, V_{GS} = 0V$ $V_{DS} = 160V, V_{GS} = 0V, T = +125^{\circ}C$ | |
| Gate-Source Leakage | IGSS | - | - | 100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS | | | | | • | · | |
| Gate Threshold Voltage | V _{GS(TH)} | 0.5 | - | 1.5 | V | $V_{DS} = V_{GS}, I_D = 1mA$ | |
| Static Drain-Source On-Resistance (Note 6) | _ | - | - | 10 | Ω | $V_{GS} = 5V, I_D = 250mA$ | |
| Static Drain-Source On-Resistance (Note 6) | R _{DS(ON)} | - | - | 10 | Ω | $V_{GS} = 3V, I_D = 125mA$ | |
| Forward Transconductance (Notes 6 & 7) | g fs | 200 | - | - | mS | $V_{DS} = 25V, I_D = 250mA$ | |
| On-State Drain Current (Note 6) | I _{D(ON)} | 500 | - | - | mA | V _{DS} = 25V, V _{GS} = 5V | |
| DYNAMIC CHARACTERISTICS (Note 7) | | | | | | · | |
| Input Capacitance | Ciss | - | - | 85 | pF | V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz | |
| Output Capacitance | Coss | - | - | 20 | pF | | |
| Reverse Transfer Capacitance | Crss | - | - | 7 | pF | | |
| Turn-On Delay Time (Note 8) | t _{D(ON)} | - | - | 8 | ns | | |
| Turn-On Rise Time (Note 8) | t _R | - | - | 8 | ns | | |
| Turn-Off Delay Time (Note 8) | t _{D(OFF)} | - | - | 20 | ns | V _{DD} = 25V, I _D = 250mA | |
| Turn-Off Fall Time (Note 8) | t _F | - | - | 12 | ns | | |

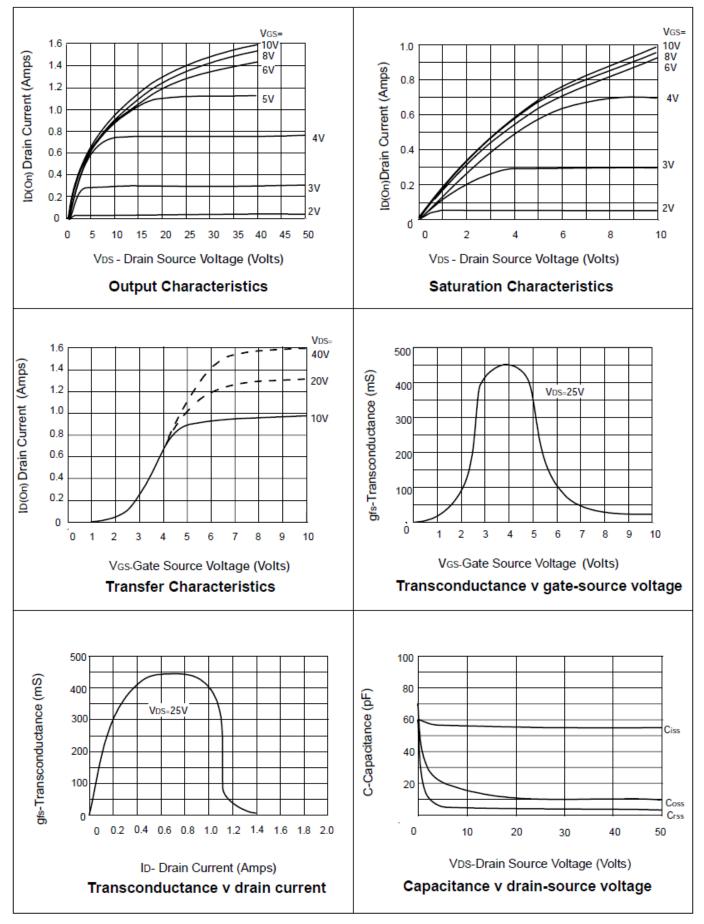
6. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

7. Sample test.

8. Switching times measured with 50 $\!\Omega$ source impedance and <5ns rise time on a pulse generator.

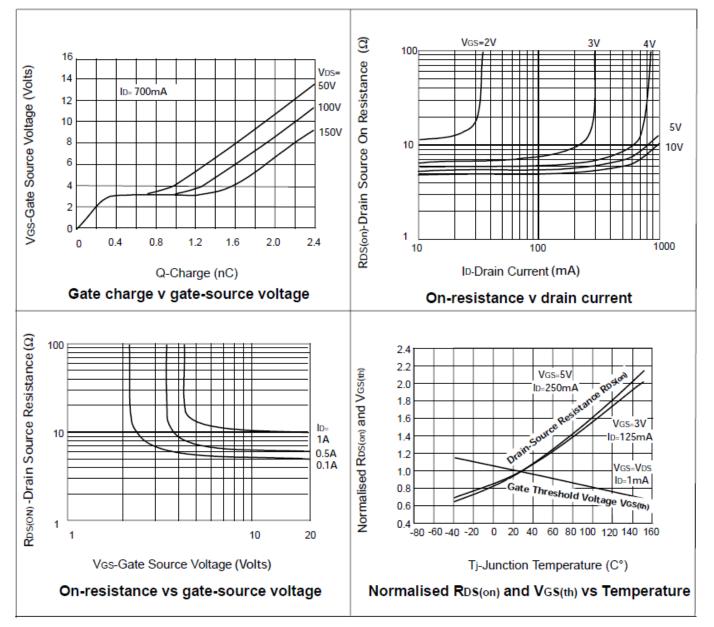


ZVNL120G





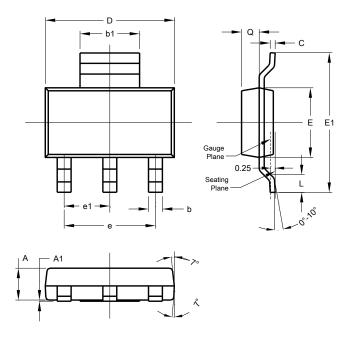






Package Outline Dimensions

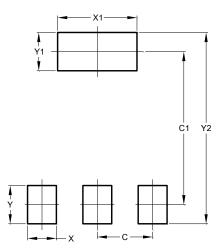
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



| | SOT223 | | | | | |
|-------|----------------------|------|------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 1.55 | 1.65 | 1.60 | | | |
| A1 | 0.010 | 0.15 | 0.05 | | | |
| b | 0.60 | 0.80 | 0.70 | | | |
| b1 | 2.90 | 3.10 | 3.00 | | | |
| С | 0.20 | 0.30 | 0.25 | | | |
| D | 6.45 | 6.55 | 6.50 | | | |
| Е | 3.45 | 3.55 | 3.50 | | | |
| E1 | 6.90 | 7.10 | 7.00 | | | |
| е | - | - | 4.60 | | | |
| e1 | - | - | 2.30 | | | |
| L | 0.85 | 1.05 | 0.95 | | | |
| Q | 0.84 | 0.94 | 0.89 | | | |
| All I | All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 2.30 |
| C1 | 6.40 |
| Х | 1.20 |
| X1 | 3.30 |
| Y | 1.60 |
| Y1 | 1.60 |
| Y2 | 8.00 |



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